

## 2.25 MHz 400-mA Step Down Converter With Selectable VOUT

### FEATURES

- High Efficiency Step Down Converter
- Output Current up to 400 mA
- $V_{IN}$  Range From 2V to 6V for Li-Ion Batteries With Extended Voltage Range
- 2.25 MHz Fixed Frequency Operation
- Pin-Selectable Fixed Output Voltage
- Power Save Mode for Highest Efficiency
- Automatic transition between PFM and PWM Mode
- Voltage Positioning in PFM Mode
- Typical 15- $\mu$ A Quiescent Current
- 100% Duty Cycle for Lowest Dropout
- Available in 2x2x0,8 mm SON Package
- Allows <1 mm Solution Height

### APPLICATIONS

- Low Power Processor Supply
- Cell Phones, Smart-phones
- Navigation Systems
- Low Power DSP Supply
- Portable Media Players
- Digital Cameras

### DESCRIPTION

The TPS62270 device is a high efficiency synchronous step down DC-DC converter optimized for battery powered portable applications. It provides up to 400 mA output current from a single Li-Ion cell.

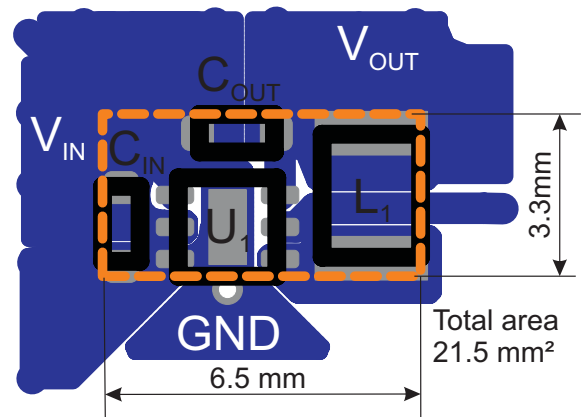
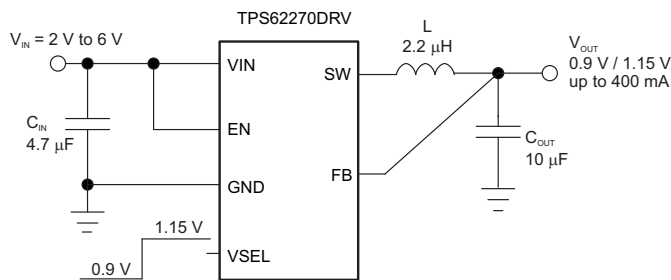
With an input voltage range of 2 V to 6 V the device supports Li-Ion batteries with extended voltage range, and is ideal to power portable applications like mobile phones and other portable equipment.

The TPS62270 operates at 2.25 MHz fixed switching frequency and enters Power Save Mode operation at light load currents to maintain high efficiency over the entire load current range. The Power Save Mode is optimized for low output voltage ripple.

With the VSEL pin, two different fixed output voltages can be selected. This function features a dynamic voltage scaling for low power processor cores.

In the shutdown mode, the current consumption is reduced to less than 1 $\mu$ A. TPS62270 allows the use of small inductors and capacitors to achieve a small solution size.

The TPS62270 is available in a 2 mm  $\times$  2 mm, 6-pin SON package.



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## ORDERING INFORMATION

T <sub>A</sub>	PART NUMBER <sup>(1)</sup>	OUTPUT VOLTAGE <sup>(2)</sup>		PACKAGE DESIGNATOR	ORDERING <sup>(1)</sup>	PACKAGE MARKING
		VSEL = 1	VSEL = 0			
–40°C to 85°C	TPS62270	1.15 V	0.9 V	DRV	TPS62270DRV	CCX
	TPS62272	3.3V	2.1V	DRV	TPS62272DRV	OAM
	TPS62273	3.3V	2.5V	DRV	TPS62273DRV	CGW

- (1) The DRV (SON2x2) package is available in tape on reel. Add R suffix to order quantities of 3000 parts per reel, add T suffix to order quantities of 250 parts per reel.  
(2) contact TI for other fixed output voltage options.

## ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

		VALUE	UNIT
Input voltage range <sup>(2)</sup>		–0.3 to 7	V
Voltage range at EN, VSEL		–0.3 to VIN +0.3, ≤7	V
Voltage on SW		–0.3 to 7	V
Peak output current		Internally limited	A
ESD rating <sup>(3)</sup>	HBM Human body model	2	kV
	CDM Charge device model	1	
	Machine model	200	V
T <sub>J</sub>	Maximum operating junction temperature	–40 to 125	°C
T <sub>stg</sub>	Storage temperature range	–65 to 150	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute–maximum–rated conditions for extended periods may affect device reliability.  
(2) All voltage values are with respect to network ground terminal.  
(3) The human body model is a 100 pF capacitor discharged through a 1.5kΩ resistor into each pin. The machine model is a 200 pF capacitor discharged directly into each pin.

## DISSIPATION RATINGS

PACKAGE	R <sub>θJA</sub>	POWER RATING FOR T <sub>A</sub> ≤ 25°C	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C
DRV	76°C/W	1300 mW	13 mW/°C

## RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
V <sub>IN</sub> Supply Voltage	2		6	V
T <sub>A</sub> Operating ambient temperature	–40		85	°C
T <sub>J</sub> Operating junction temperature	–40		125	°C

## ELECTRICAL CHARACTERISTICS

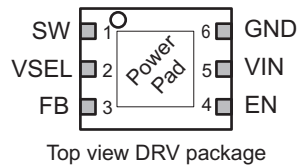
Over full operating ambient temperature range, typical values are at  $T_A = 25^\circ\text{C}$ . Unless otherwise noted, specifications apply for condition  $V_{IN} = EN = 3.6\text{V}$ . External components  $C_{IN} = 4.7\mu\text{F}$  0603,  $C_{OUT} = 10\mu\text{F}$  0603,  $L = 2\mu\text{H}$ , see the parameter measurement information.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT		
SUPPLY								
V <sub>IN</sub>	Input voltage range		2		6	V		
I <sub>OUT</sub>	Output current	2.5 V ≤ V <sub>IN</sub> ≤ 6 V			400	mA		
		2 V ≤ V <sub>IN</sub> ≤ 2.5 V			150			
I <sub>Q</sub>	Operating quiescent current	I <sub>OUT</sub> = 0 mA, device not switching		15		μA		
		I <sub>OUT</sub> = 0 mA, device switching with no load, V <sub>OUT</sub> = 1.15V		18				
I <sub>SD</sub>	Shutdown current	EN = GND	0.1		1	μA		
UVLO	Undervoltage lockout threshold	Falling	1.85			V		
		Rising	1.95					
ENABLE, VSEL								
V <sub>IH</sub>	High level input voltage, EN, VSEL	2 V ≤ V <sub>IN</sub> ≤ 6 V	1		V <sub>IN</sub>	V		
V <sub>IL</sub>	Low Level Input Voltage, EN, VSEL	2 V ≤ V <sub>IN</sub> ≤ 6 V	0		0.4	V		
I <sub>IN</sub>	Input bias Current, EN, VSEL	EN, VSEL = GND or V <sub>IN</sub>	0.01		1.0	μA		
POWER SWITCH								
R <sub>DS(on)</sub>	High side MOSFET on-resistance	V <sub>IN</sub> = V <sub>GS</sub> = 3.6V, T <sub>A</sub> = 25°C	240		480	mΩ		
	Low side MOSFET on-resistance	V <sub>IN</sub> = V <sub>GS</sub> = 3.6V, T <sub>A</sub> = 25°C	180		380	mΩ		
I <sub>LIMF</sub>	Forward current limit MOSFET high-side and low side	V <sub>IN</sub> = V <sub>GS</sub> = 3.6 V	0.56	0.7	0.84	A		
T <sub>SD</sub>	Thermal shutdown	Increasing junction temperature	140			°C		
	Thermal shutdown hysteresis	Decreasing junction temperature	20					
OSCILLATOR								
f <sub>SW</sub>	Oscillator frequency	2 V ≤ V <sub>IN</sub> ≤ 6 V	2	2.25	2.5	MHz		
OUTPUT								
V <sub>OUT</sub>	Output voltage PWM	TPS62270	PWM operation, 2 V ≤ V <sub>IN</sub> ≤ 6 V, FB pin connected to V <sub>OUT</sub> <sup>(1)</sup>	VSEL = 1	1.13	1.15	1.16 7	V
				VSEL = 0	0.88 6	0.9	0.91 4	
		TPS62272	PWM operation, 2 V ≤ V <sub>IN</sub> ≤ 6 V, FB pin connected to V <sub>OUT</sub> <sup>(1)</sup>	VSEL = 1	3.23	3.3	3.37	
				VSEL = 0	2.06	2.1	2.14	
		TPS62273	PWM operation, FB pin connected to V <sub>OUT</sub> <sup>(1)</sup>	VSEL = 1	3.23	3.3	3.37	
				VSEL = 0	2.45	2.5	2.55	
V <sub>OUT</sub>	Output voltage in PFM mode, voltage positioning	TPS62270		VSEL = 1		1.16	V	
				VSEL = 0		0.91		
		TS62272		VSEL = 1		3.34		
				VSEL = 0		2.12		
		TPS62273		VSEL = 1		3.34		
				VSEL = 0		2.53		
t <sub>Start</sub>	Start-up time	Time from active EN to reach 95% of V <sub>OUT</sub>			500	μs		
t <sub>Ramp</sub>	V <sub>OUT</sub> ramp up time	Time to ramp from 5% to 95% of V <sub>OUT</sub>			250	μs		
I <sub>IQ</sub>	Leakage Current into SW pin	V <sub>IN</sub> = 3.6 V, V <sub>IN</sub> = V <sub>OUT</sub> = V <sub>SW</sub> , EN = GND <sup>(2)</sup>			0.1	1	μA	

(1) For  $V_{IN} = V_{OUT} + 0.6\text{ V}$

(2) In fixed output voltage versions, the internal resistor divider network is disconnected from FB pin.

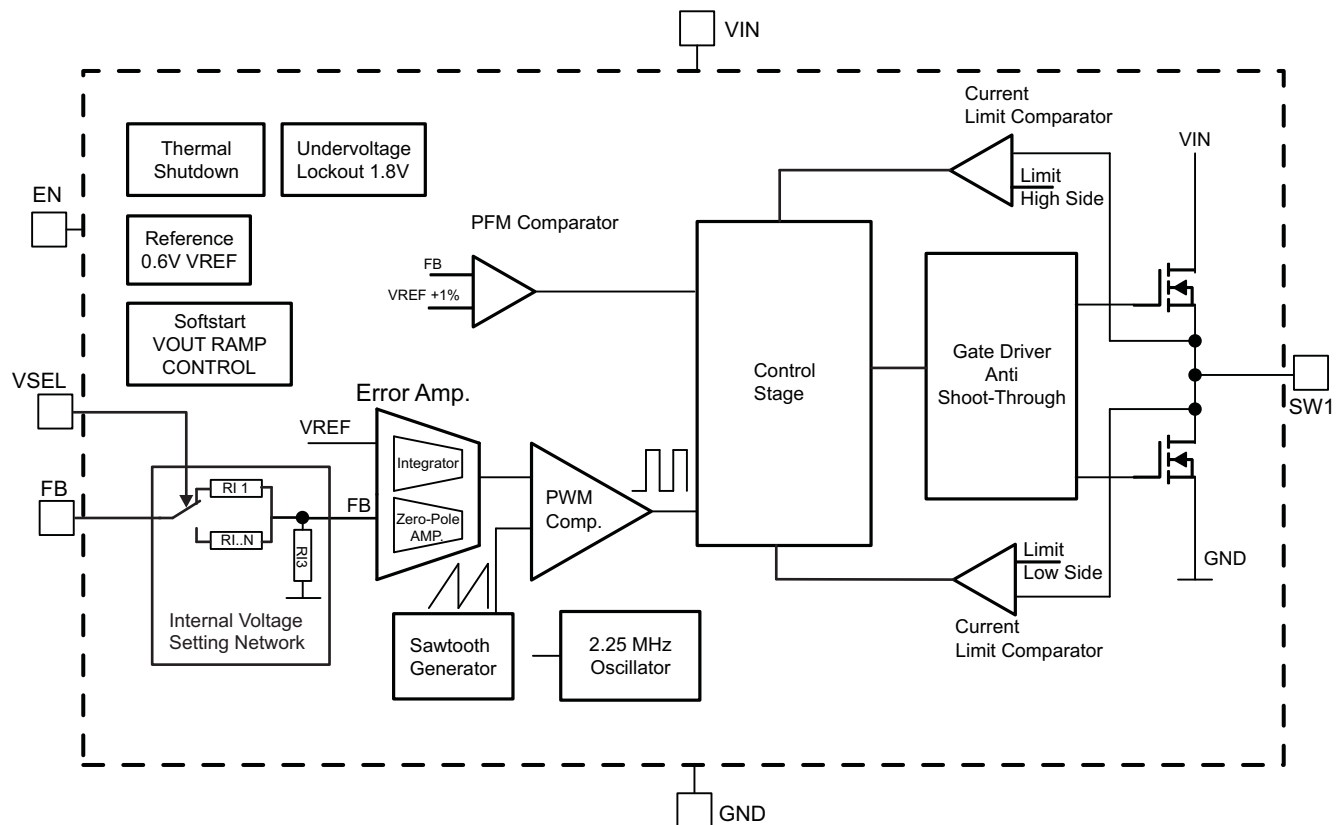
## PIN ASSIGNMENTS



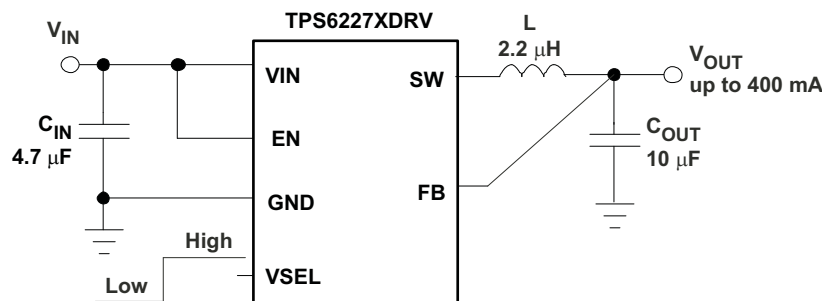
## TERMINAL FUNCTIONS

TERMINAL		I/O	DESCRIPTION
NAME	NO. (SON)		
V <sub>IN</sub>	5	PWR	V <sub>IN</sub> power supply pin.
GND	6	PWR	GND supply pin
EN	4	I	This is the enable pin of the device. Pulling this pin to low forces the device into shutdown mode. Pulling this pin to high enables the device. This pin must be terminated.
SW	1	OUT	This is the switch pin and is connected to the internal MOSFET switches. Connect the inductor to this terminal
FB	3	I	Feedback Pin for the internal regulation loop. Connect the external resistor divider to this pin. In case of fixed output voltage option, connect this pin directly to the output capacitor
VSEL	2	I	Voltage Select input. Please refer to table ordering information for available output voltage selections.

## FUNCTIONAL BLOCK DIAGRAM



## PARAMETER MEASUREMENT INFORMATION



L: MIPSA2520D2R2 2.0  $\mu$ H  
 $C_{IN}$ : GRM188R60J106M 4.7  $\mu$ F  
 $C_{OUT}$ : GRM188R60J106M 10  $\mu$ F

## TYPICAL CHARACTERISTICS

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Static Drain Source On-state Resistance	vs Input Voltage	<a href="#">Figure 22</a>
Static Drain Source On-state Resistance	vs Input Voltage	<a href="#">Figure 23</a>

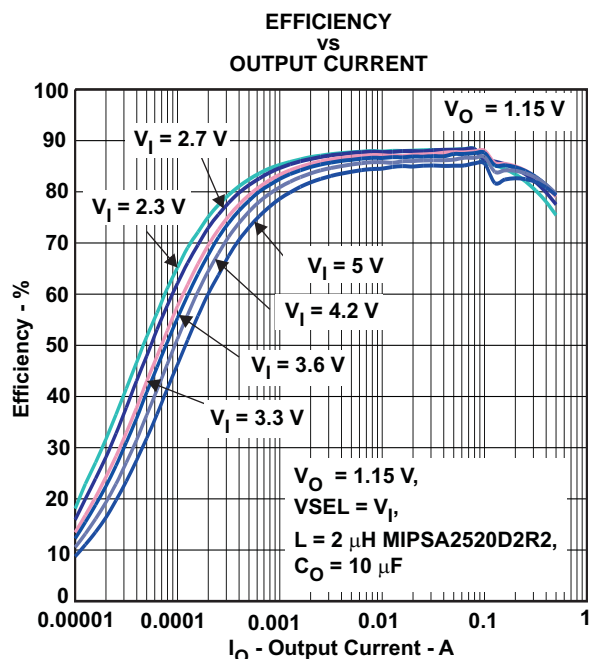


Figure 1.

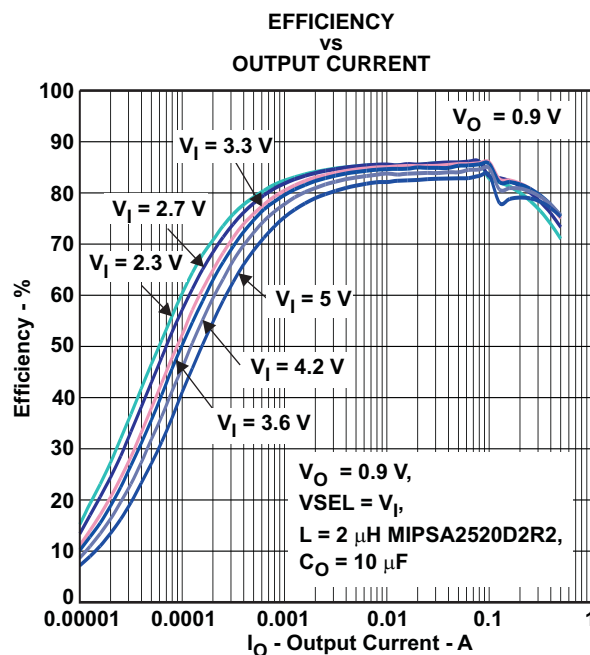


Figure 2.

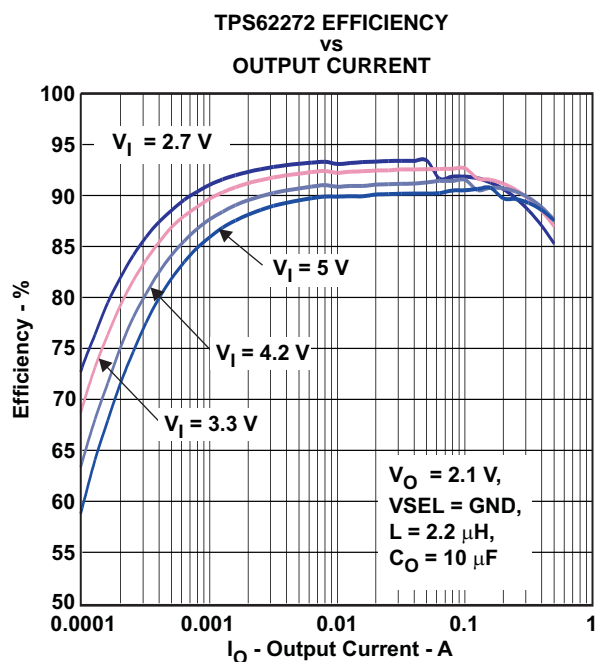


Figure 3.

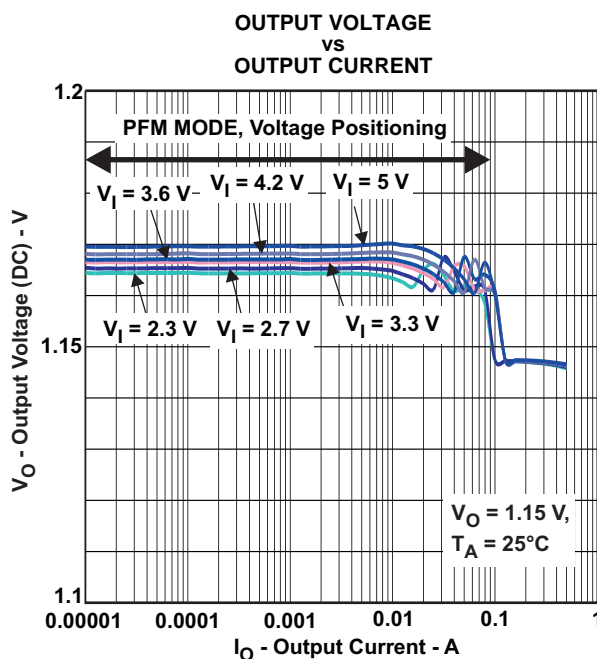


Figure 4.

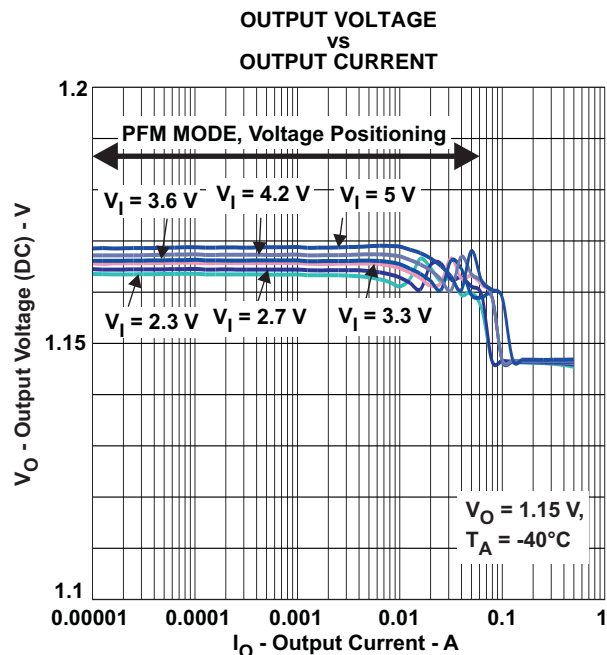


Figure 5.

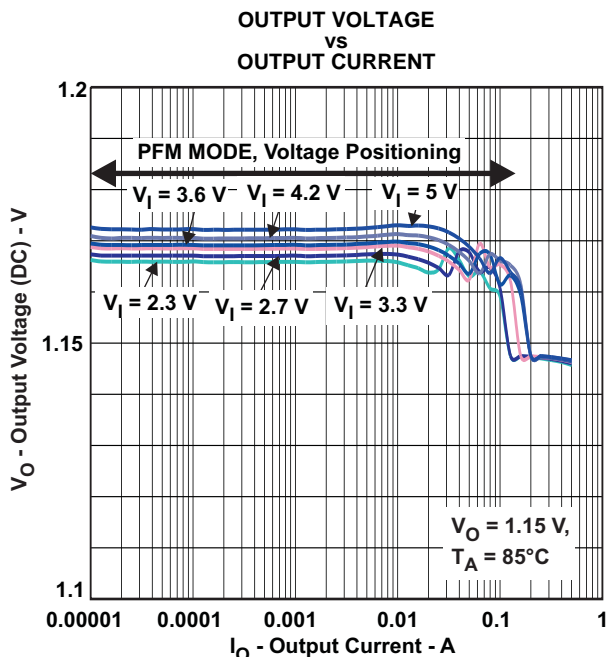


Figure 6.

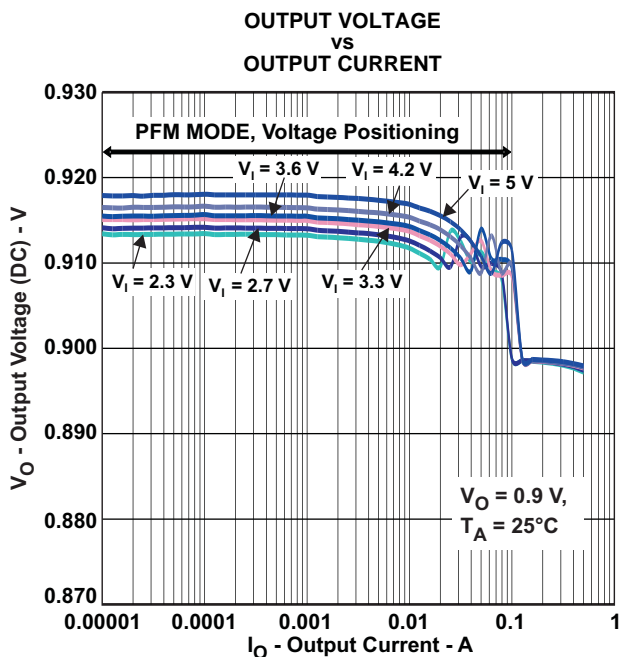


Figure 7.

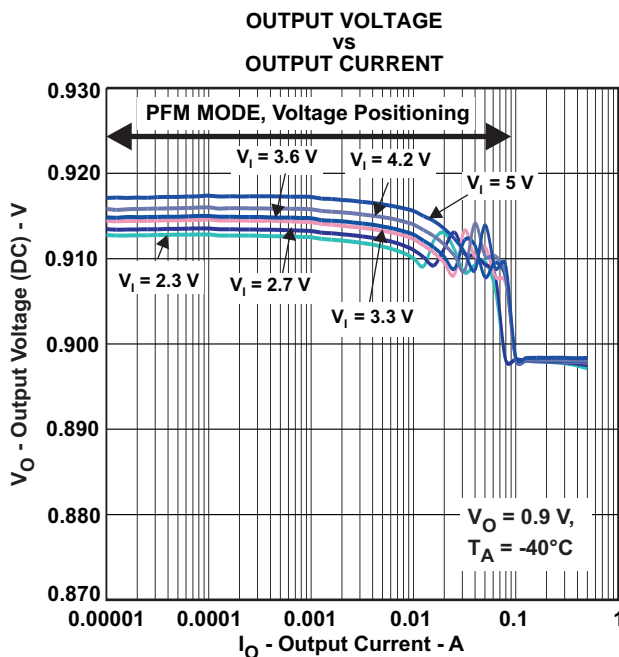
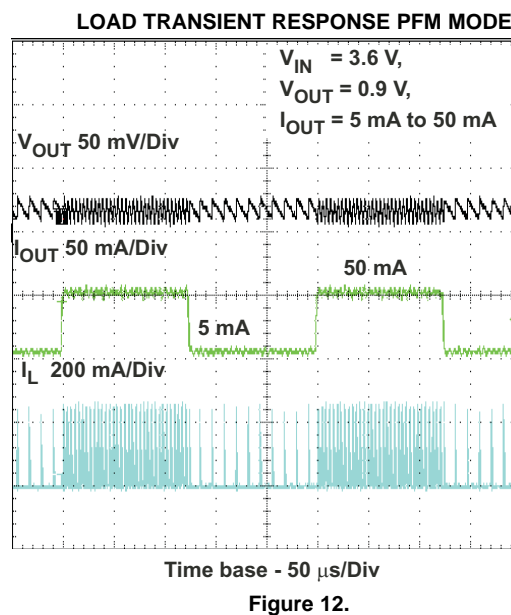
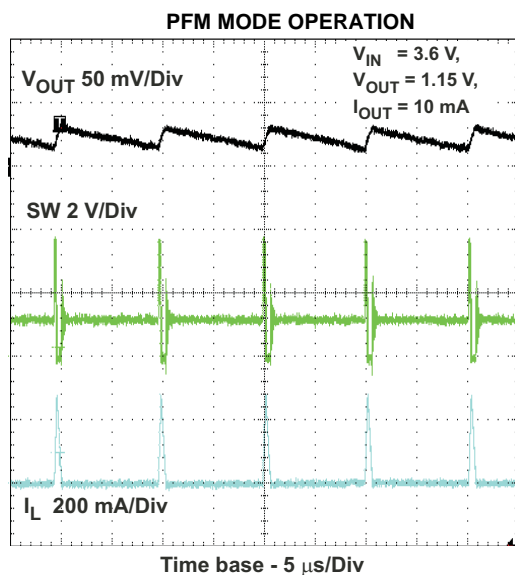
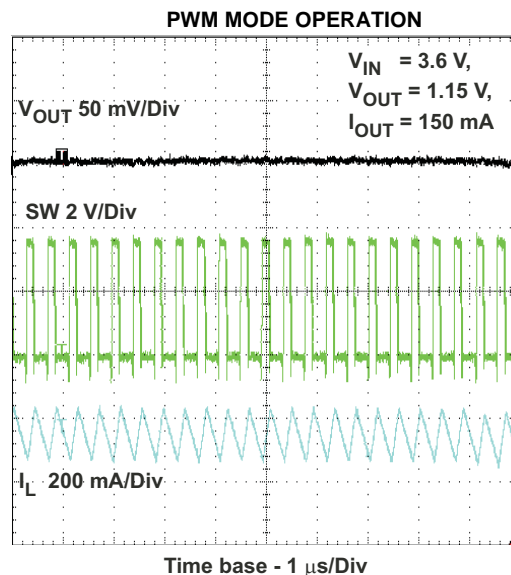
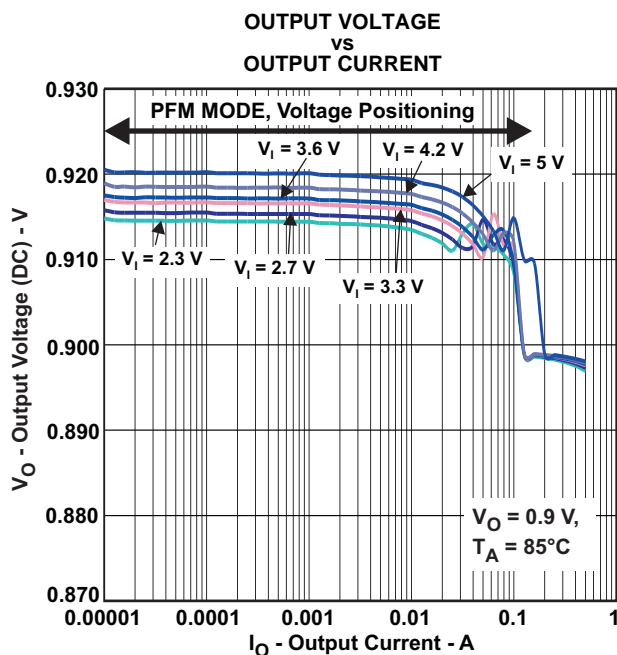
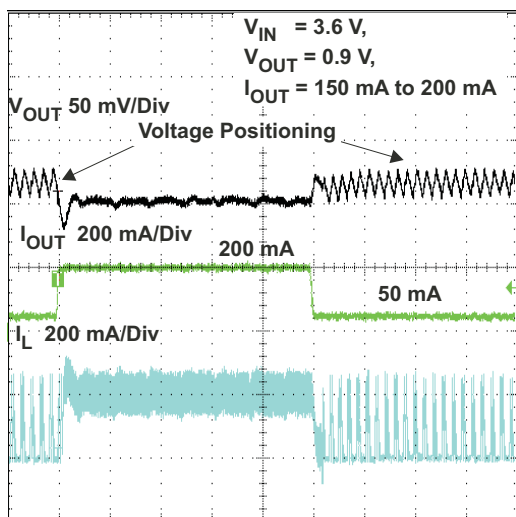


Figure 8.





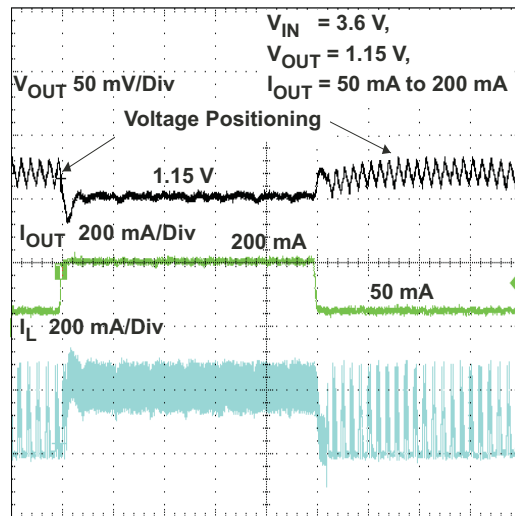
**LOAD TRANSIENT RESPONSE PFM/PWM MODE**



Time base - 20  $\mu$ s/Div

**Figure 13.**

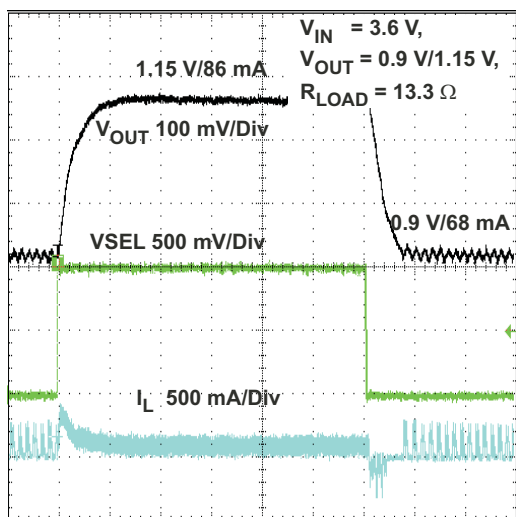
**LOAD TRANSIENT RESPONSE PFM/PWM MODE**



Time base - 20  $\mu$ s/Div

**Figure 14.**

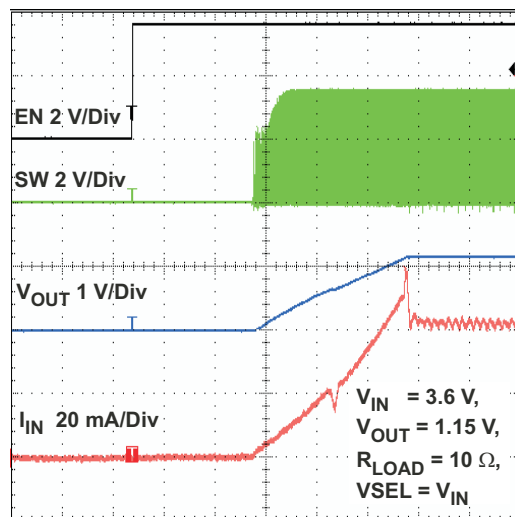
**VSEL OUTPUT VOLTAGE RESPONSE**



Time base - 20  $\mu$ s/Div

**Figure 15.**

**STARTUP IN 10  $\Omega$  LOAD  
AT 1.15 V OUTPUT VOLTAGE**



Time base - 100  $\mu$ s/Div

**Figure 16.**

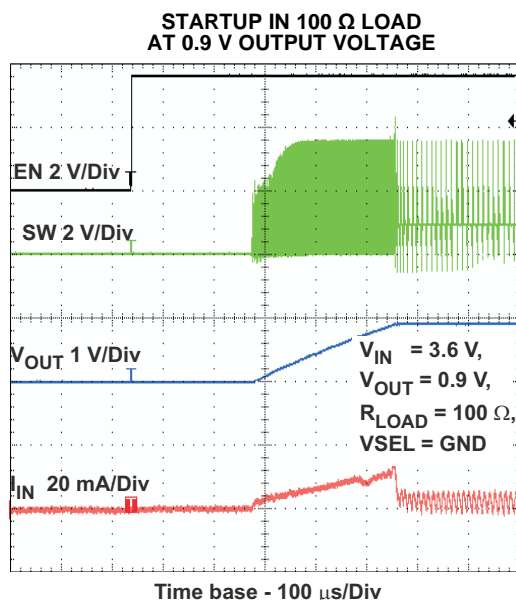


Figure 17.

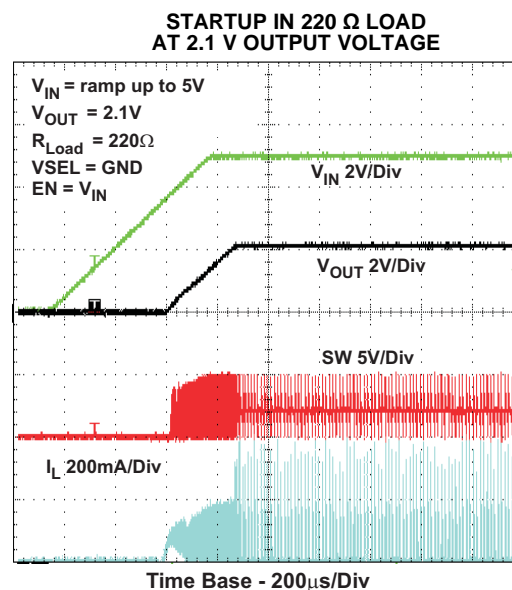


Figure 18.

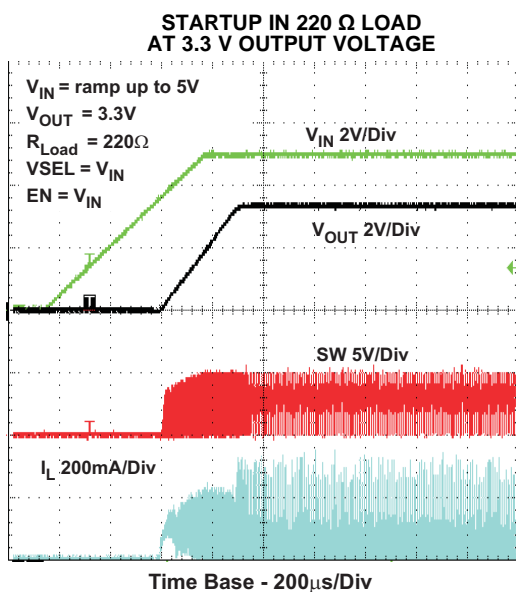


Figure 19.

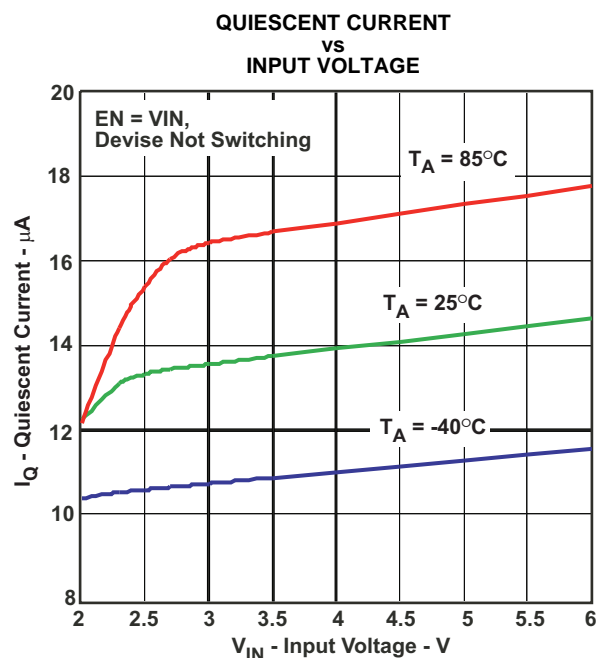


Figure 20.

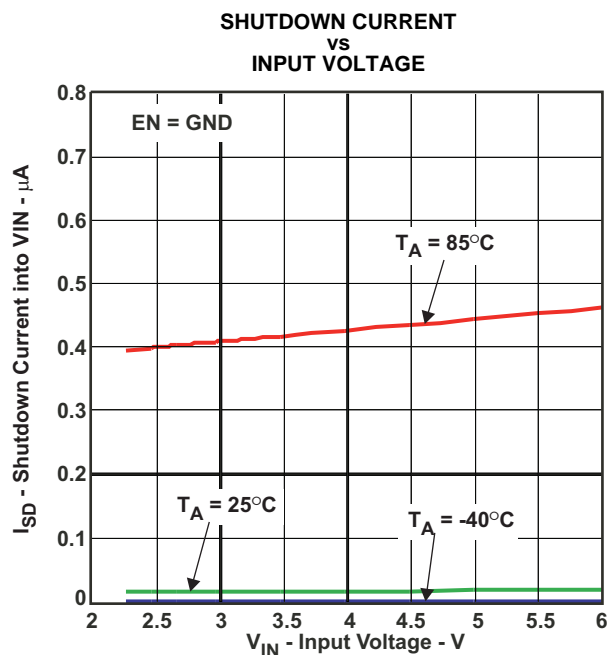


Figure 21.

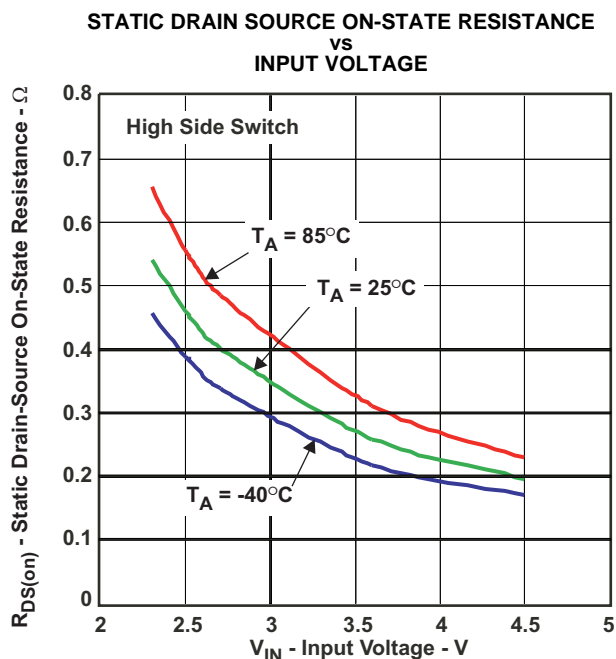


Figure 22.

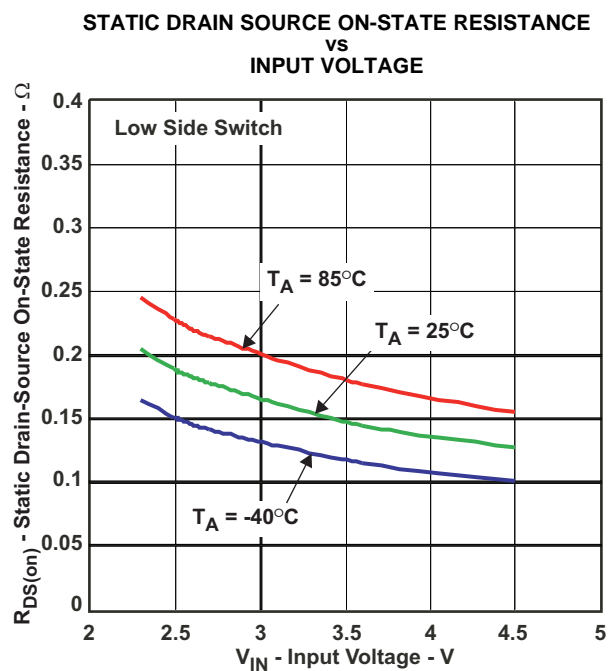


Figure 23.

## DETAILED DESCRIPTION

### OPERATION

The TPS62270 step down converter operates with typically 2.25 MHz fixed frequency pulse width modulation (PWM) at moderate to heavy load currents. At light load currents the converter automatically enters Power Save Mode and operates then in PFM mode.

During PWM operation the converter use a unique fast response voltage mode controller scheme with input voltage feed-forward to achieve good line and load regulation allowing the use of small ceramic input and output capacitors. At the beginning of each clock cycle initiated by the clock signal, the High Side MOSFET switch is turned on. The current flows now from the input capacitor via the High Side MOSFET switch through the inductor to the output capacitor and load. During this phase, the current ramps up until the PWM comparator trips and the control logic will turn off the switch. The current limit comparator will also turn off the switch in case the current limit of the High Side MOSFET switch is exceeded. After a dead time preventing shoot through current, the Low Side MOSFET rectifier is turned on and the inductor current will ramp down. The current flows now from the inductor to the output capacitor and to the load. It returns back to the inductor through the Low Side MOSFET rectifier.

The next cycle will be initiated by the clock signal again turning off the Low Side MOSFET rectifier and turning on the on the High Side MOSFET switch.

### Power Save Mode

If the load current decreases, the converter will enter Power Save Mode operation automatically. During Power Save Mode the converter skips switching and operates with reduced frequency in PFM mode with a minimum quiescent current to maintain high efficiency.

The transition from PWM mode to PFM mode occurs once the inductor current in the Low Side MOSFET switch becomes zero, which indicates discontinuous conduction mode.

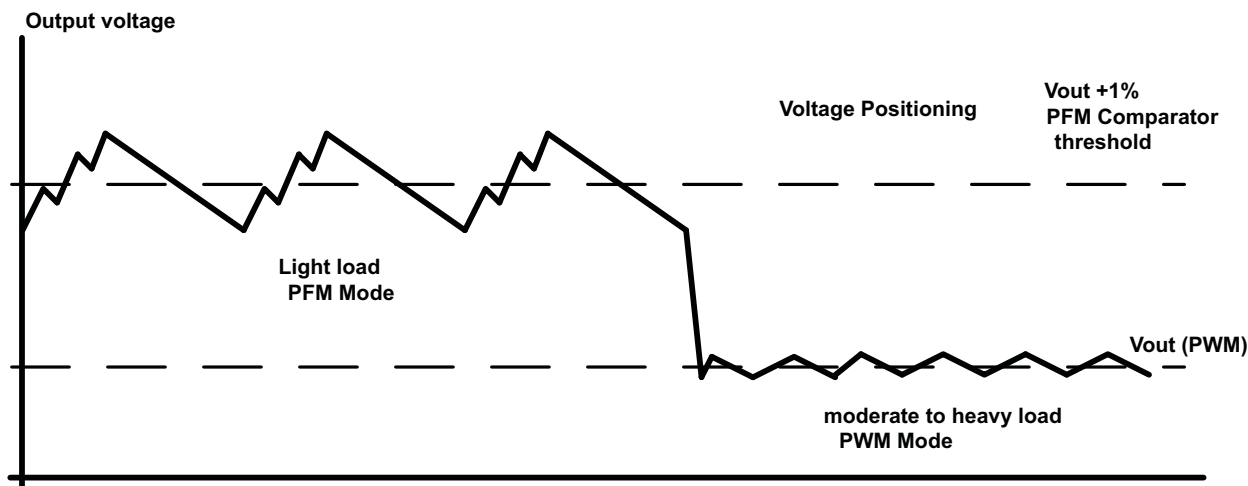
During the Power Save Mode the output voltage is monitored with a PFM comparator. As the output voltage falls below the PFM comparator threshold of  $V_{OUT} + 1\%$ , the device starts a PFM current pulse. For this the High Side MOSFET switch will turn on and the inductor current ramps up. After the On-time expires the switch will be turned off and the Low Side MOSFET switch will be turned on until the inductor current becomes zero.

The converter effectively delivers a current to the output capacitor and the load. If the load is below the delivered current the output voltage will rise. If the output voltage is equal or higher than the PFM comparator threshold, the device stops switching and enters a sleep mode with typical 15 $\mu$ A current consumption.

In case the output voltage is still below the PFM comparator threshold, further PFM current pulses will be generated until the PFM comparator threshold is reached. The converter starts switching again once the output voltage drops below the PFM comparator threshold.

With a fast single threshold comparator, the output voltage ripple during PFM mode operation can be kept very small. The PFM Pulse is timing controlled, which allows to modify the charge transferred to the output capacitor by the value of the inductor. The resulting PFM output voltage ripple depends in first order on the size of the output capacitor and the inductor value. Increasing output capacitor values and/or inductor values will minimize the output ripple.

The PFM mode is left and PWM mode entered in case the output current can not longer be supported in PFM mode.



**Figure 24. Power Save Mode**

### 100% Duty Cycle Low Dropout Operation

The device starts to enter 100% duty cycle Mode once the input voltage comes close the nominal output voltage. In order to maintain the output voltage, the High Side MOSFET switch is turned on 100% for one or more cycles.

With further decreasing VIN the High Side MOSFET switch is turned on completely. In this case the converter offers a low input-to-output voltage difference. This is particularly useful in battery-powered applications to achieve longest operation time by taking full advantage of the whole battery voltage range.

The minimum input voltage to maintain regulation depends on the load current and output voltage, and can be calculated as:

$$V_{in_{min}} = V_{out_{max}} + I_{out_{max}} \times (R_{DS(on)_{max}} + R_L)$$

With

$I_{out_{max}}$  = maximum output current plus inductor ripple current

$R_{DS(on)_{max}}$  = maximum P-channel switch  $R_{DS(on)}$ .

$R_L$  = DC resistance of the inductor

$V_{out_{max}}$  = nominal output voltage plus maximum output voltage tolerance

### Undervoltage Lockout

The undervoltage lockout circuit prevents the device from malfunctioning at low input voltages and from excessive discharge of the battery and disables the output stage of the converter. The undervoltage lockout threshold is typically 1.85V with falling VIN.

### Output Voltage Selection VSEL

The VSEL pin features output voltage selection. The output voltages are set with an internal high precision feedback divider network. No further external components for output voltage setting or compensation are required. This features smallest solution size.

Connecting the VSEL pin to an external logic control signal allows simple dynamic voltage scaling for low power processors cores. During operation of the device, the output voltage can be changed with VSEL pin.

This allows setting the core voltage of an processor according to its operating mode and helps to optimize power consumption. [Table 1](#) shows an overview of the selectable output voltages.

**Table 1. VSEL Output Voltage Selection**

DEVICE	OUTPUT VOLTAGE VOUT	
	VSEL = low	VSEL = high
TPS62270	0.9 V	1.15 V
TPS62272	2.1V	3.3V
TPS62273	2.5V	3.3V

### Enable

The device is enabled setting EN pin to high. During the start up time  $t_{\text{Start up}}$  the internal circuits are settled. Afterwards the device activates the soft start circuit. The EN input can be used to control power sequencing in a system with various DC/DC converters. The EN pin can be connected to the output of another converter, to drive the EN pin high and getting a sequencing of supply rails.

### Soft Start

The TPS62270 has an internal soft start circuit that controls the ramp up of the output voltage. The output voltage ramps up from 5% to 95% of its nominal value within typ. 250 $\mu$ s. This limits the inrush current in the converter during start up and prevents possible input voltage drops when a battery or high impedance power source is used. The Soft start circuit is enabled after the start up time  $t_{\text{Start up}}$  has expired.

### Short-Circuit Protection

The High Side and Low Side MOSFET switches are short-circuit protected with maximum output current =  $I_{\text{LIMF}}$ . Once the High Side MOSFET switch reaches its current limit, it is turned off and the Low Side MOSFET switch is turned on. The High Side MOSFET switch can only turn on again, once the current in the Low Side MOSFET switch decreases below its current limit.

### Thermal Shutdown

As soon as the junction temperature,  $T_J$ , exceeds 150°C (typical) the device goes into thermal shutdown. In this mode, the High Side and Low Side MOSFETs are turned-off. The device continues its operation when the junction temperature falls below the thermal shutdown hysteresis.

## APPLICATION INFORMATION

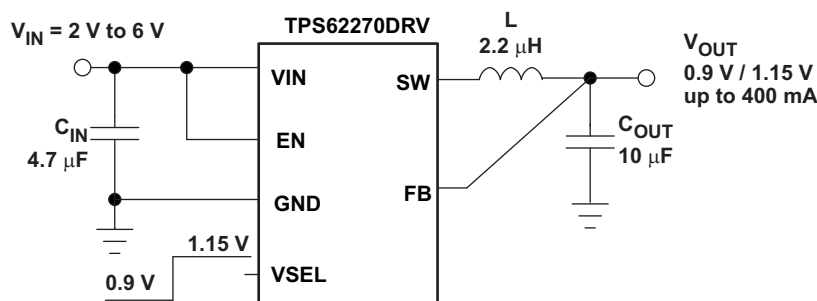


Figure 25. TPS62270DRV Application Circuit

## OUTPUT FILTER DESIGN (INDUCTOR AND OUTPUT CAPACITOR)

The TPS62270 is designed to operate with inductors in the range of 1.5μH to 4.7μH and with output capacitors in the range of 4.7μF to 22μF. The part is optimized for operation with a 2.2μH inductor and 10μF output capacitor. Larger or smaller inductor values can be used to optimize the performance of the device for specific operation conditions. For stable operation, the L and C values of the output filter may not fall below 1μH effective inductance and 3.5μF effective capacitance.

### Inductor Selection

The inductor value has a direct effect on the ripple current. The selected inductor has to be rated for its dc resistance and saturation current. The inductor ripple current ( $\Delta I_L$ ) decreases with higher inductance and increases with higher  $V_I$  or  $V_O$ .

The inductor selection has also impact on the output voltage ripple in PFM mode. Higher inductor values will lead to lower output voltage ripple and higher PFM frequency, lower inductor values will lead to a higher output voltage ripple but lower PFM frequency.

[Equation 1](#) calculates the maximum inductor current under static load conditions. The saturation current of the inductor should be rated higher than the maximum inductor current as calculated with [Equation 2](#). This is recommended because during heavy load transient the inductor current will rise above the calculated value.

$$\Delta I_L = V_{out} \times \frac{1 - \frac{V_{out}}{V_{in}}}{L \times f} \quad (1)$$

$$I_{Lmax} = I_{outmax} + \frac{\Delta I_L}{2} \quad (2)$$

With:

f = Switching Frequency (2.25 MHz typical)

L = Inductor Value

$\Delta I_L$  = Peak to Peak inductor ripple current

$I_{Lmax}$  = Maximum Inductor current

A more conservative approach is to select the inductor current rating just for the maximum switch current of the corresponding converter.

Accepting larger values of ripple current allows the use of low inductance values, but results in higher output voltage ripple, greater core losses, and lower output current capability.

The total losses of the coil have a strong impact on the efficiency of the DC/DC conversion and consist of both the losses in the dc resistance ( $R_{DC}$ ) and the following frequency-dependent components:

- The losses in the core material (magnetic hysteresis loss, especially at high switching frequencies)
- Additional losses in the conductor from the skin effect (current displacement at high frequencies)
- Magnetic field losses of the neighboring windings (proximity effect)
- Radiation losses

**Table 2. List of Inductors**

DIMENSIONS [mm <sup>3</sup> ]	INDUCTOR TYPE	SUPPLIER
2.5 × 2.0 × 1.0	MIPS2520	FDK
2.5 × 2.0 × 1.2	MIPSA2520	FDK
2.5 × 2.0 × 1.0	KSLI-252010AG2R2	Hitachi Metals
2.5 × 2.0 × 1.2	LQM2HPN2R2MJ0L	Murata

### Output Capacitor Selection

The advanced fast-response voltage mode control scheme of the TPS62270 allows the use of tiny ceramic capacitors. Ceramic capacitors with low ESR values have the lowest output voltage ripple and are recommended. The output capacitor requires either an X7R or X5R dielectric. Y5V and Z5U dielectric capacitors, aside from their wide variation in capacitance over temperature, become resistive at high frequencies.

At nominal load current, the device operates in PWM mode and the RMS ripple current is calculated as:

$$I_{\text{RMS Cout}} = V_{\text{out}} \times \frac{1 - \frac{V_{\text{out}}}{V_{\text{in}}}}{L \times f} \times \frac{1}{2 \times \sqrt{3}} \quad (3)$$

At nominal load current, the device operates in PWM mode and the overall output voltage ripple is the sum of the voltage spike caused by the output capacitor ESR plus the voltage ripple caused by charging and discharging the output capacitor:

$$\Delta V_{\text{out}} = V_{\text{out}} \times \frac{1 - \frac{V_{\text{out}}}{V_{\text{in}}}}{L \times f} \times \left( \frac{1}{8 \times C_{\text{out}} \times f} + \text{ESR} \right) \quad (4)$$

At light load currents the converter operates in Power Save Mode and the output voltage ripple is dependent on the output capacitor and inductor value. Larger output capacitor and inductor values minimize the voltage ripple in PFM mode and tighten DC output accuracy in PFM mode.

### Input Capacitor Selection

An input capacitor is required for best input voltage filtering, and minimizing the interference with other circuits caused by high input voltage spikes. For most applications, a 4.7μF to 10μF ceramic capacitor is recommended. Because ceramic capacitor loses up to 80% of its initial capacitance at 5 V, it is recommended that 10μF input capacitors be used for input voltages >4.5V. The input capacitor can be increased without any limit for better input voltage filtering. Take care when using only small ceramic input capacitors. When a ceramic capacitor is used at the input and the power is being supplied through long wires, such as from a wall adapter, a load step at the output or VIN step on the input can induce ringing at the VIN pin. This ringing can couple to the output and be mistaken as loop instability or could even damage the part by exceeding the maximum ratings.

**Table 3. List of Capacitors**

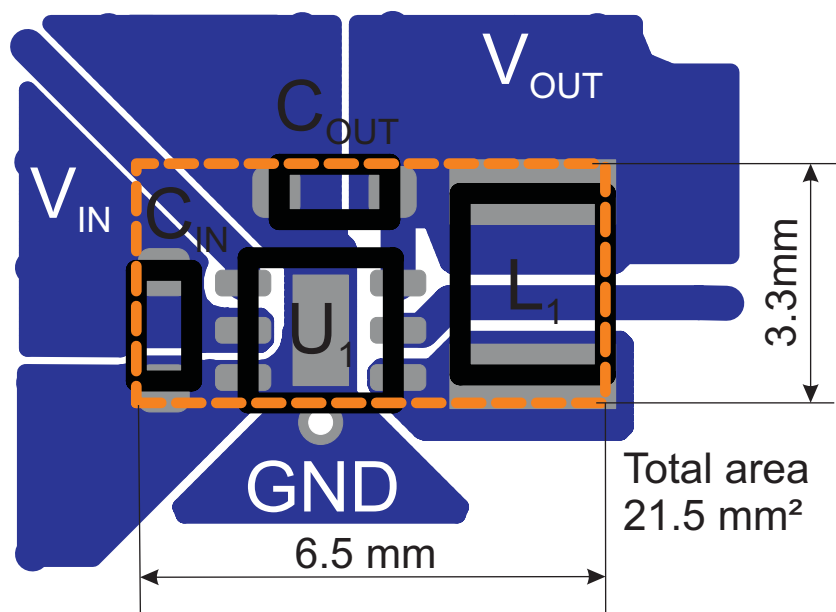
CAPACITANCE	TYPE	SIZE mm <sup>3</sup>	SUPPLIER
4.7 μF	GRM188R60J475K	0603: 1.6 × 0.8 × 0.8 mm <sup>3</sup>	Murata
10 μF	GRM188R60J106M69D	0603: 1.6 × 0.8 × 0.8 mm <sup>3</sup>	Murata



## LAYOUT CONSIDERATIONS

As for all switching power supplies, the layout is an important step in the design. Proper function of the device demands careful attention to PCB layout. Care must be taken in board layout to get the specified performance. If the layout is not carefully done, the regulator could show poor line and/or load regulation, stability issues as well as EMI problems. It is critical to provide a low inductance, impedance ground path. Therefore, use wide and short traces for the main current paths. The input capacitor should be placed as close as possible to the IC pins as well as the inductor and output capacitor.

Connect the GND Pin of the device to the PowerPad™ of the PCB and use this pad as a star point. Use a common Power GND node and a different node for the Signal GND to minimize the effects of ground noise. Connect these ground nodes together to the PowerPad™ (star point) underneath the IC. Keep the common path to the GND PIN, which returns the small signal components and the high current of the output capacitors as short as possible to avoid ground noise. The FB line should be connected right to the output capacitor and routed away from noisy components and traces (e.g., SW line).



**Figure 26. Suggested Board Layout**

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TPS62270DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CCX	<a href="#">Samples</a>
TPS62270DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CCX	<a href="#">Samples</a>
TPS62270DRV/T	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CCX	<a href="#">Samples</a>
TPS62270DRV/TG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CCX	<a href="#">Samples</a>
TPS62272DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	OAM	<a href="#">Samples</a>
TPS62272DRV/T	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	OAM	<a href="#">Samples</a>
TPS62273DRVR	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGW	<a href="#">Samples</a>
TPS62273DRVRG4	ACTIVE	SON	DRV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGW	<a href="#">Samples</a>
TPS62273DRV/T	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGW	<a href="#">Samples</a>
TPS62273DRV/TG4	ACTIVE	SON	DRV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGW	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

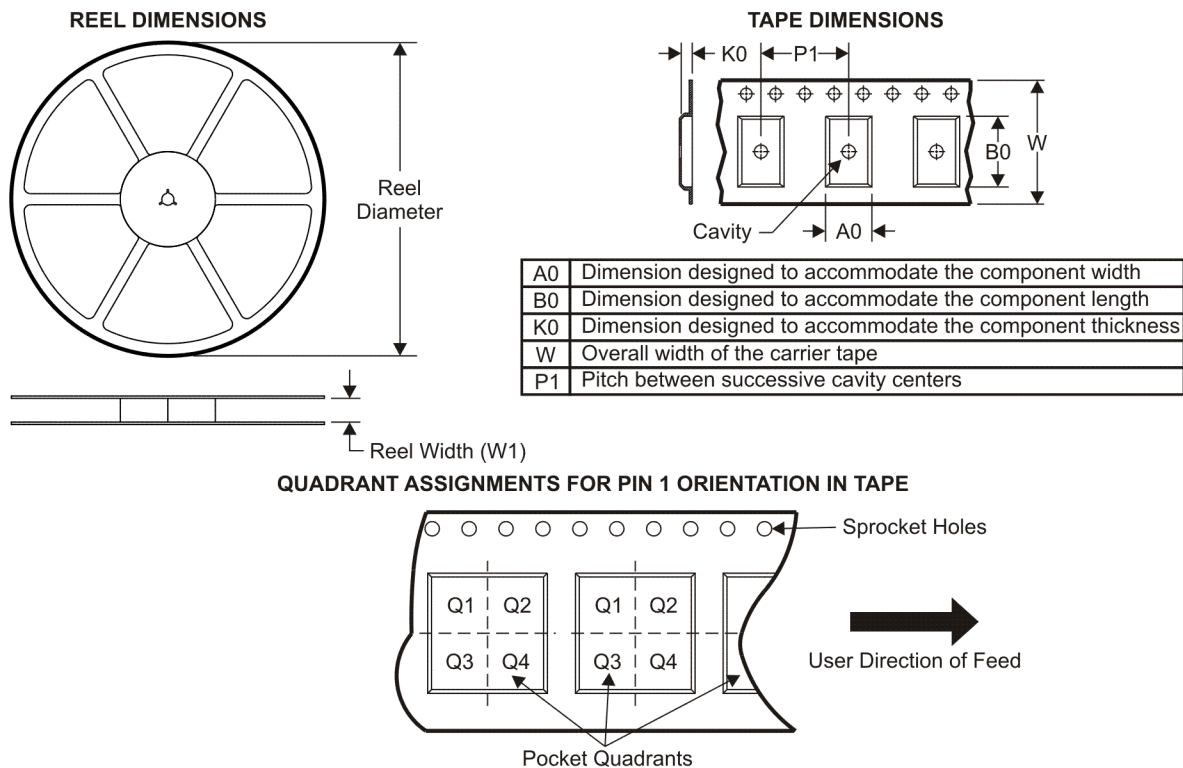
**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS62270DRV	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62270DRV	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62272DRV	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62272DRV	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62273DRV	SON	DRV	6	3000	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2
TPS62273DRV	SON	DRV	6	250	179.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS62270DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS62270DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS62272DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS62272DRVT	SON	DRV	6	250	203.0	203.0	35.0
TPS62273DRVR	SON	DRV	6	3000	203.0	203.0	35.0
TPS62273DRVT	SON	DRV	6	250	203.0	203.0	35.0

DRV (S-PWSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



4206925/E 10/10

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Small Outline No-Lead (SON) package configuration.
  -  D. The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.

## THERMAL PAD MECHANICAL DATA

DRV (S-PWSON-N6)

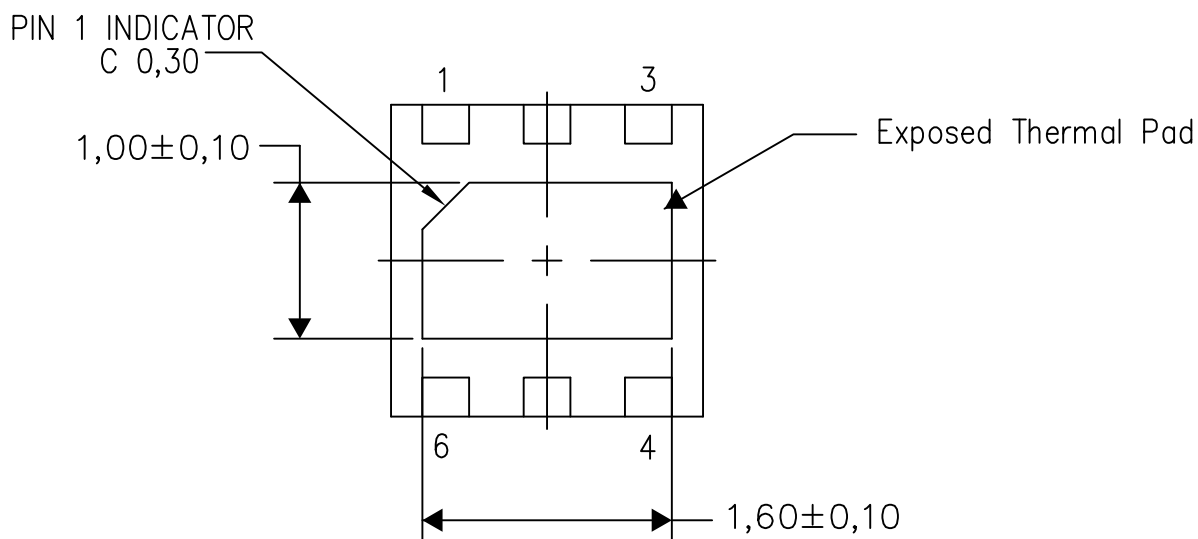
PLASTIC SMALL OUTLINE NO-LEAD

### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

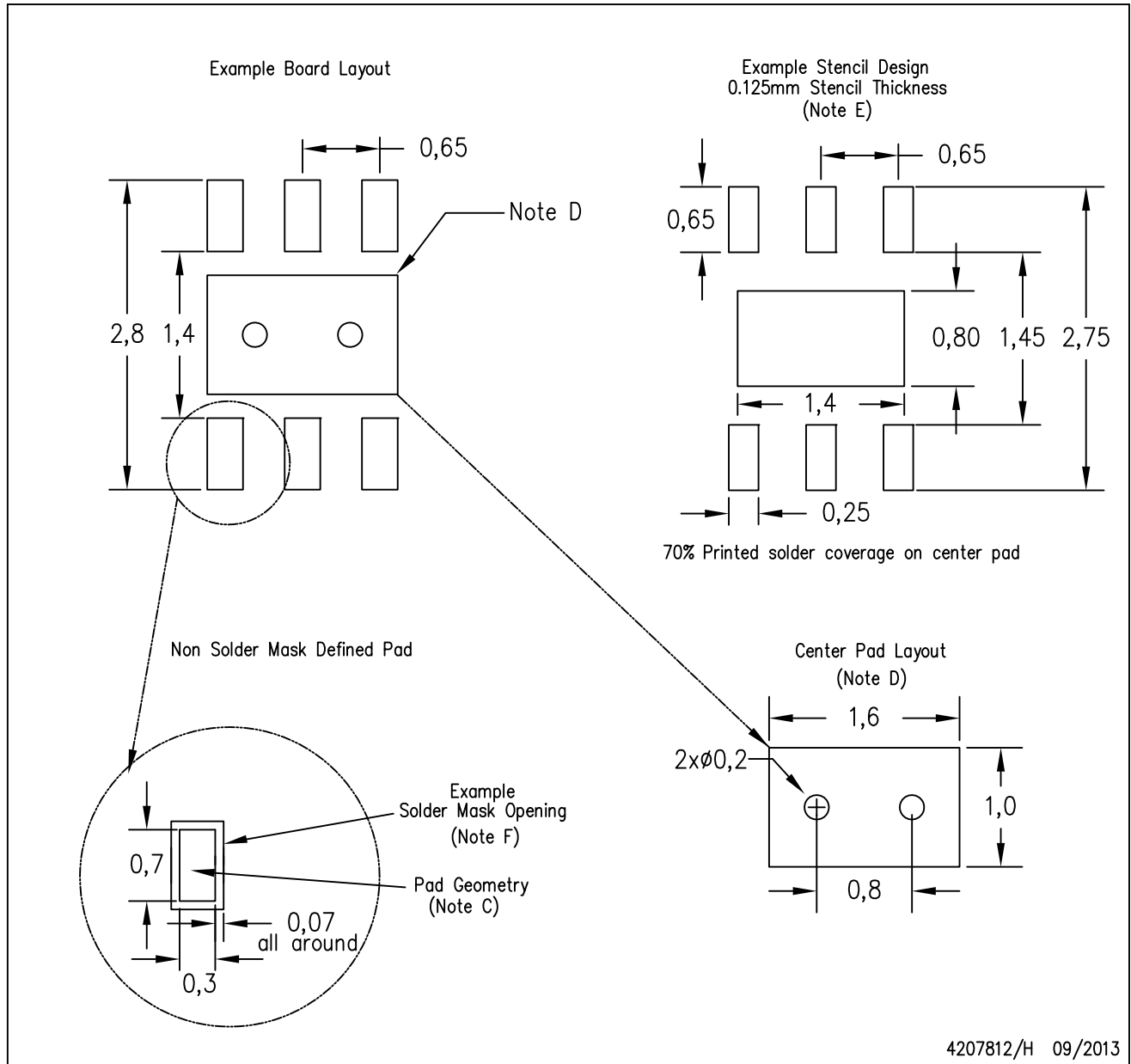
Exposed Thermal Pad Dimensions

4206926/N 03/13

NOTE: All linear dimensions are in millimeters

DRV (S-PWSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - F. Customers should contact their board fabrication site for solder mask tolerances.



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